

LTVS16H16T5G

1-Line Uni-directional TVS Diode

The LTVS16H16T5G is an uni-directional TVS diode, Fast turn-on and Low ESD clamping voltage, Solid-state silicon-avalanche and active circuit triggering technology. The LTVS16H16T5G complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. The high ESD surge protection make 16H16T5G an ideal choice to Power Supply Protection, Notebooks and Handhelds, Touch Panels, Cellular Handsets and Accessories.

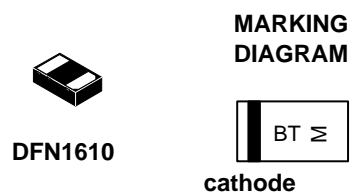
Features

- Protects one data or power line
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: $\pm 30\text{kV}$
 Contact discharge: $\pm 30\text{kV}$
- We declare that the material of product compliance with RoHS requirements and Halogen Free.

Applications

- Peripherals
- Touch Panels
- Power Line Protection
- Small Panel Modules
- Hand Held Portable Applications

LTVS16H16T5G



BT = Specific Device Code
M = Month Code

Ordering information

Device	Marking	Packing
LTVS16H16T5G	BT	DFN1610-2A

LTVS16H16T5G

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	1740	W
Peak Pulse Current (8/20 μs)	Ipp	60	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	± 30 ± 30	kV
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			16	V	
Breakdown Voltage	VBR	17.6		20	V	$I_R = 1\text{mA}$
Reverse Leakage Current	I_R			0.5	μA	$V_R = 16\text{V}$
Clamping Voltage	V_C		20		V	$I_{PP} = 10\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C		28	29	V	$I_{PP} = 60\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	CJ		390		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

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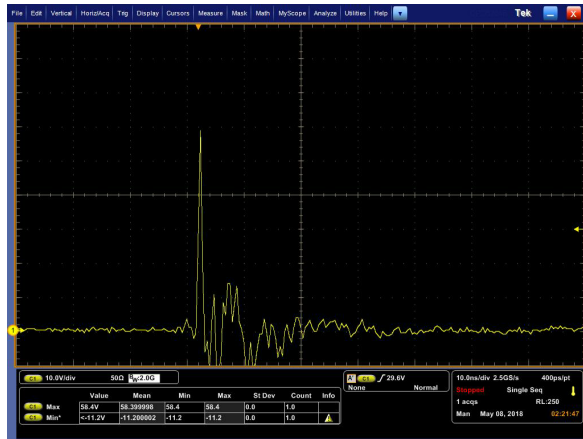


Figure 1. ESD Clamping Voltage Screenshot
Positive 8 kV Contact per IEC61000-4-2

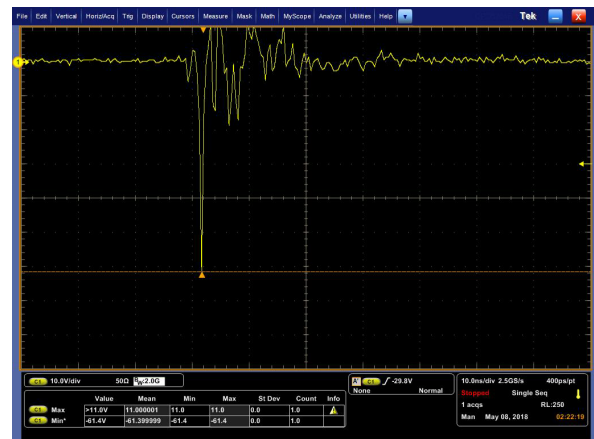
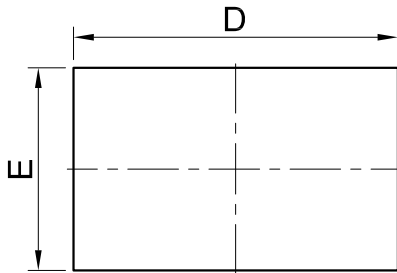


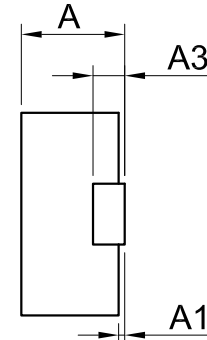
Figure 2. ESD Clamping Voltage Screenshot
Negative 8 kV Contact per IEC61000-4-2

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OUTLINE AND DIMENSIONS

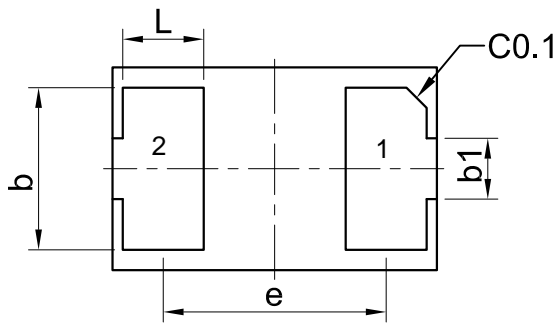


TOP VIEW



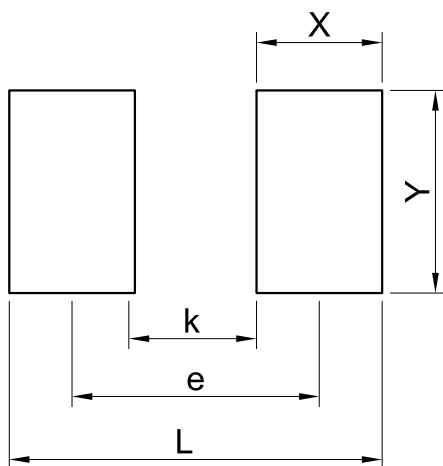
SIDE VIEW

DFN1610			
DIM	MIN	NOR	MAX
A	0.46	0.51	0.56
A1	0.01	0.03	0.05
b	0.75	0.80	0.85
b1	0.25	0.30	0.35
D	1.55	1.60	1.65
E	0.95	1.00	1.05
e	1.10BSC		
L	0.35	0.40	0.45
A3	0.127REF.		
All Dimensions in mm			



BOTTOM VIEW

SOLDERING FOOTPRINT



DFN1610	
DIM	(mm)
X	0.62
Y	1.00
L	1.84
e	1.22
K	0.60

DISCLAIMER

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